

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C (Note 10)	
60V	$3.1m\Omega$ @ $V_{GS} = 10V$	100A	

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- Low Q_a Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Description and Applications

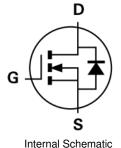
This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

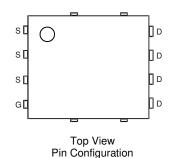
- DC Motor Control
- Synchronous Rectification
- DC-DC Converters

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 ²
- Weight: 0.097 grams (Approximate)







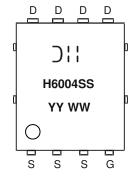
Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH6004SPSQ-13	PowerDI5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



⊃¦¦ = Manufacturer's Marking H6004SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 18 = 2018) WW = Week (01 to 53)

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	60	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 6)	I _D	25 21	Α	
Continuous Drain Current (Notes 7 & 10)	I _D	100 100	Α	
Maximum Continuous Body Diode Forward Current (Note 6)		Is	100	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	400	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	I _{SM}	400	Α	
Avalanche Current, L=0.2mH	I _{AS}	45	Α	
Avalanche Energy, L=0.2mH	E _{AS}	200	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	P_{D}	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	47	°C/W
Total Power Dissipation (Note 7)	$T_C = +25^{\circ}C$	P_D	167	W
Thermal Resistance, Junction to Case (Note 7)		R _{eJC}	0.9	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage		BV _{DSS}	60	-	-	٧	$V_{GS} = 0V$, $I_D = 1mA$
Zoro Cata Voltago Drain Current		I _{DSS}	-	-	1	μA	$V_{DS} = 48V$, $V_{GS} = 0V$
Zero Gate Voltage Drain Current	(Note 9)		-	-	100	μΑ	$V_{DS} = 48V, V_{GS} = 0V, T_{J} = +125^{\circ}C$
Gate-Source Leakage		I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage		$V_{GS(TH)}$	2	-	4	٧	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance		R _{DS(ON)}	ı	2.5	3.1	mΩ	$V_{GS} = 10V, I_D = 50A$
Diode Forward Voltage		V_{SD}	-	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance		C _{iss}	-	4556	-		
Output Capacitance Reverse Transfer Capacitance		Coss	1	1383	-	pF	$V_{DS} = 30V$, $V_{GS} = 0V$, $f = 1MHz$
		Crss	-	105.2	-		
Gate Resistance		R_g	0.1	0.66	1.9	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge		Qg	-	95.4	-		V 20V I 20A
Gate-Source Charge		Q_{gs}	-	21.6	-	nC	$V_{DD} = 30V, I_D = 90A,$ $V_{GS} = 10V$
Gate-Drain Charge		Q_{gd}	-	20.4	-		V _{GS} = 10V
Turn-On Delay Time		t _{D(ON)}	-	13.2	-		
Turn-On Rise Time		t _R	-	11.7	-	ns	$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 90A, R_{G} = 3.5\Omega$
Turn-Off Delay Time Turn-Off Fall Time		t _{D(OFF)}	-	31	-		
		t _F	-	12	-		
Body Diode Reverse Recovery Time		t _{RR}	-	50.5	-	ns	L 504 di/dt 1004/up
Body Diode Reverse Recovery Charge		Q _{RR}	-	80.8	-	nC	l _F = 50A, di/dt = 100A/μs

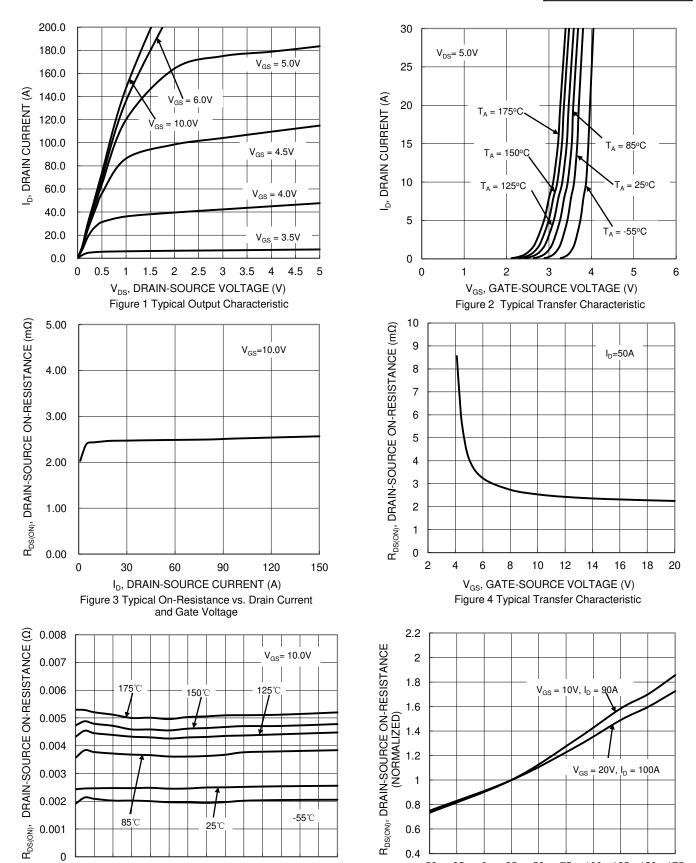
Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to product testing.

- 10. Package limited.







I_D, DRAIN CURRENT (A) Figure 5 Typical On-Resistance vs. Drain Current and Temperature

10 20 30 40 50 60 70 80 90 100110120130140150

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T_., JUNCTION TEMPERATURE (°C)

25 50

-50 -25

100 125 150 175





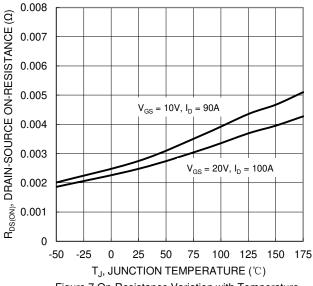


Figure 7 On-Resistance Variation with Temperature

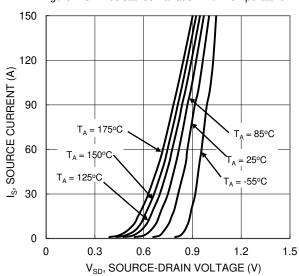
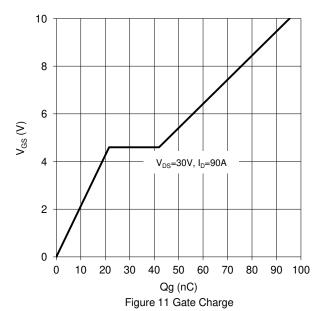
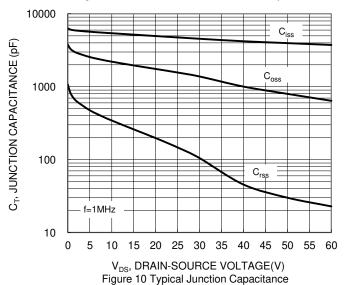


Figure 9 Diode Forward Voltage vs. Current



3 $V_{GS(TH)}, \text{ GATE THRESHOLD VOLTAGE }(V)$ 2.5 $I_D = 1mA$ 2 $I_{D} = 250 \mu A$ 1.5 1 0.5 -50 -25 25 50 75 100 125 150 175 T_J , JUNCTION TEMPERATURE (°C)

Figure 8 Gate Threshold Variation vs. Temperature



1000 $R_{\text{DS}(\text{ON})}$ Limited 100 ID, DRAIN CURRENT (A) 10 $P_W = 10ms$ $P_W = 100 \mu s$ $T_{J(Max)} = 175^{\circ}C$ $T_C = 25^{\circ}C$ $P_W = 10 \mu s$ Single Pulse DUT on Infinite Heatsink $V_{GS} = 10V$ 0.1 0.1 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



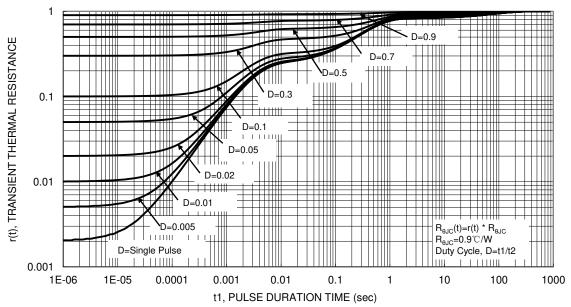


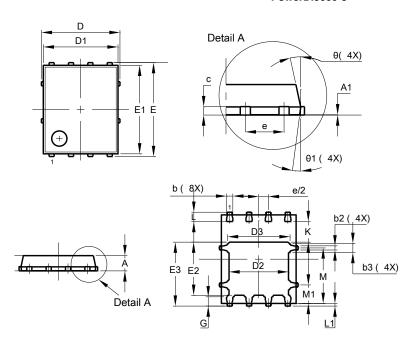
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

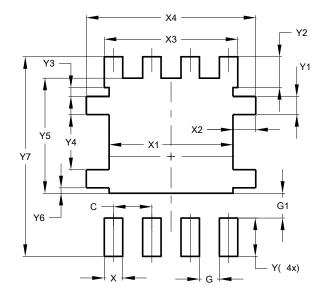


PowerDI5060-8						
Dim	Min	Тур				
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
Е	(6.15 BSC	;			
E1	5.60	6.00 5.8				
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	_	_			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10⁰	12º	11º			
Θ1	6º	8º	7º			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Υ	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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